NSN 5961-01-265-8135

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-265-8135 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.175 inches **Overall Height:** 0.073 inches **Overall Width:** 0.073 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc and 75.0 working peak reverse voltage **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminals silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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